

## Electronic Acknowledgement Receipt

<b>EFS ID:</b>	8561653
<b>Application Number:</b>	10575625
<b>International Application Number:</b>	
<b>Confirmation Number:</b>	4644
<b>Title of Invention:</b>	Group-III nitride semiconductor device
<b>First Named Inventor/Applicant Name:</b>	Hiromitsu Sakai
<b>Customer Number:</b>	23373
<b>Filer:</b>	Abraham Jacob Rosner/Cora Flanagan
<b>Filer Authorized By:</b>	Abraham Jacob Rosner
<b>Attorney Docket Number:</b>	Q78084
<b>Receipt Date:</b>	05-OCT-2010
<b>Filing Date:</b>	13-APR-2006
<b>Time Stamp:</b>	13:34:17
<b>Application Type:</b>	U.S. National Stage under 35 USC 371

### Payment information:

Submitted with Payment	no
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### File Listing:

Document Number	Document Description	File Name	File Size(Bytes)/ Message Digest	Multi Part /.zip	Pages (if appl.)
1		Q78084_IDS.PDF	141950 e3471b57e1619640fde622e4c3955b82cec416e3	yes	4

	Multipart Description/PDF files in .zip description				
	Document Description		Start	End	
	Transmittal Letter		1	2	
	Information Disclosure Statement (IDS) Filed (SB/08)		3	4	
Warnings:					
Information:					
2	Foreign Reference	EP_1_160_882.PDF	2604628	no	16
			08aab71f17eb5a5ea0581d398e37ea6b3fd65c39		
Warnings:					
Information:					
3	NPL Documents	TAKEUCHI_ET_AL_Improvement_of_far-field_pattern_ETC.PDF	711227	no	3
			a97829b9ec81f9ee7ee739368951a7673022bf5e		
Warnings:					
Information:					
4	NPL Documents	ADELMANN_ET_AL_Atomic-layer_epitaxy_of_GaN_quantum_wells_ETC.PDF	942184	no	3
			70aa9ba4f4bb6bd7f8f02dd89460081b9c3bf95d		
Warnings:					
Information:					
5	NPL Documents	MIYAMURA_ET_AL_Stranski-Krastanow_growth_of_GaN_quantum_dots_ETC.PDF	685343	no	4
			e126aa94d89da2670a196db39b559d7d9693fe51		
Warnings:					
Information:					
6	NPL Documents	HUANG_ET_AL_Defect_reduction_with_quantum_dots_in_GaN_ETC.PDF	946272	no	3
			66e28a1cace053d91e654a04596eac147c4b2914		
Warnings:					
Information:					
7	NPL Documents	Supplemental_European_Search_Report_EP04792622.PDF	676951	no	5
			1464e9154475f3614f02da37647efd01364223b3		
Warnings:					
Information:					
Total Files Size (in bytes):			6708555		

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**New Applications Under 35 U.S.C. 111**

**If a new application is being filed and the application includes the necessary components for a filing date (see 37 CFR 1.53(b)-(d) and MPEP 506), a Filing Receipt (37 CFR 1.54) will be issued in due course and the date shown on this Acknowledgement Receipt will establish the filing date of the application.**

**National Stage of an International Application under 35 U.S.C. 371**

**If a timely submission to enter the national stage of an international application is compliant with the conditions of 35 U.S.C. 371 and other applicable requirements a Form PCT/DO/EO/903 indicating acceptance of the application as a national stage submission under 35 U.S.C. 371 will be issued in addition to the Filing Receipt, in due course.**

**New International Application Filed with the USPTO as a Receiving Office**

**If a new international application is being filed and the international application includes the necessary components for an international filing date (see PCT Article 11 and MPEP 1810), a Notification of the International Application Number and of the International Filing Date (Form PCT/RO/105) will be issued in due course, subject to prescriptions concerning national security, and the date shown on this Acknowledgement Receipt will establish the international filing date of the application.**